

NCE N-Channel Super Trench Power MOSFET

Description

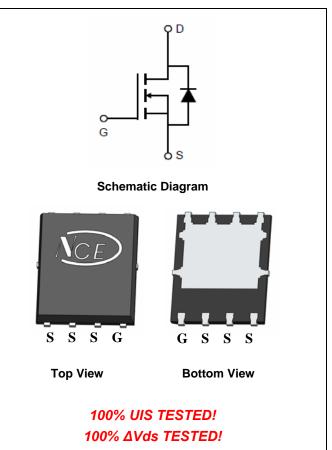
The NCEP01T10G uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

- V_{DS} =100V,I_D =105A
 - $R_{DS(ON)}$ =6.2m Ω (typical) @ V_{GS}=10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|------------|----------------|-----------|------------|----------|
| P01T10G | NCEP01T10G | DFN5X6-8L | - | - | - |

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|----------------------------------|------------|------|
| Drain-Source Voltage | Vds | 100 | V |
| Gate-Source Voltage | Vgs | ±20 | V |
| Drain Current-Continuous | Ι _D | 105 | А |
| Drain Current-Continuous(T _C =100℃) | I _D (100℃) | 74 | А |
| Pulsed Drain Current | I _{DM} | 400 | А |
| Maximum Power Dissipation | PD | 140 | W |
| Derating factor | | 1.12 | W/℃ |
| Single pulse avalanche energy (Note 5) | E _{AS} | 676 | mJ |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 150 | °C |
| Thermal Characteristic | | | |
| Thermal Resistance, Junction-to-Case ^(Note 2) | R _{θJC} | 0.89 | °C/W |



Electrical Characteristics (T_c=25[°]C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|---------------------|---|-----|------|------|------|
| Off Characteristics | ···· | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 100 | | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =100V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | ···· | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2.5 | - | 4.5 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V_{GS} =10V, I _D =50A | - | 6.2 | 7.0 | mΩ |
| Forward Transconductance | g fs | V _{DS} =10V,I _D =50A | 40 | - | - | S |
| Dynamic Characteristics (Note4) | · · | | · | | | |
| Input Capacitance | C _{lss} | | - | 4300 | - | PF |
| Output Capacitance | C _{oss} | V _{DS} =50V,V _{GS} =0V, F=1.0MHz | - | 790 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | | - | 47 | - | PF |
| Switching Characteristics (Note 4) | · · · · · | | - | | | |
| Turn-on Delay Time | t _{d(on)} | V _{DD} =50V,I _D =50A V _{GS} =10V,R _G =4.7Ω | - | 13 | - | nS |
| Turn-on Rise Time | tr | | - | 58 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | | - | 39 | - | nS |
| Turn-Off Fall Time | t _f | | - | 8 | - | nS |
| Total Gate Charge | Qg | V _{DS} =50V,I _D =50A, | - | 60 | | nC |
| Gate-Source Charge | Q _{gs} | | - | 21 | | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 11 | | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =50A | - | | 1.2 | V |
| Diode Forward Current (Note 2) | I _S | | - | - | 105 | А |
| Reverse Recovery Time | t _{rr} | $T_J = 25^{\circ}C, I_F = I_S$ | - | 60 | | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs ^(Note3) | - | 140 | | nC |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.

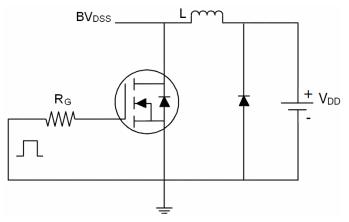
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25\Omega

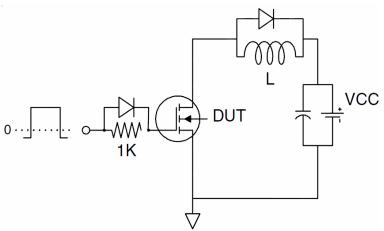


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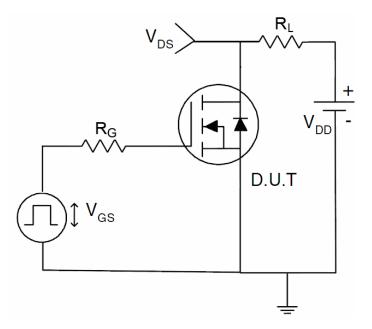
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

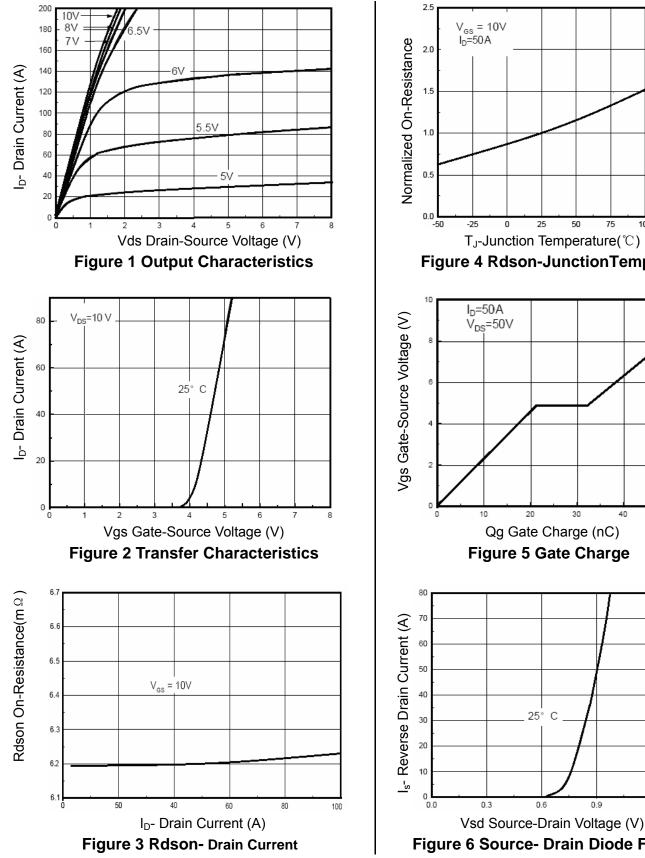


3) Switch Time Test Circuit









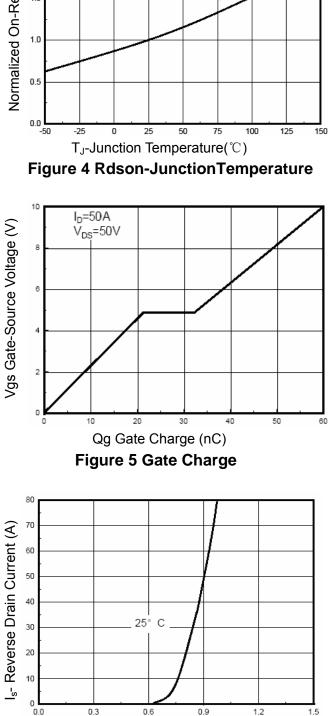


Figure 6 Source- Drain Diode Forward

0.6

1.5



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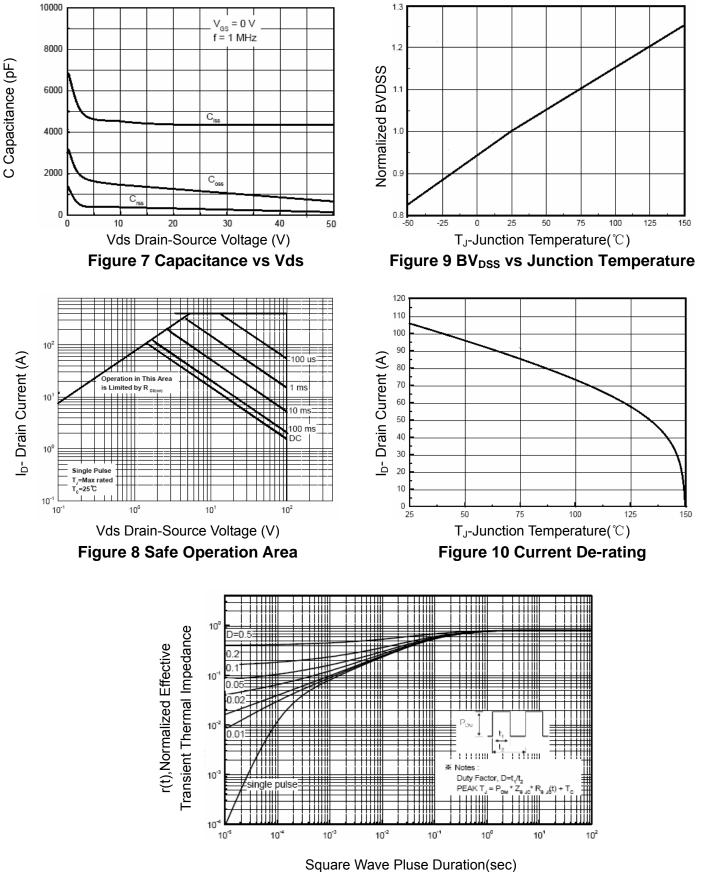
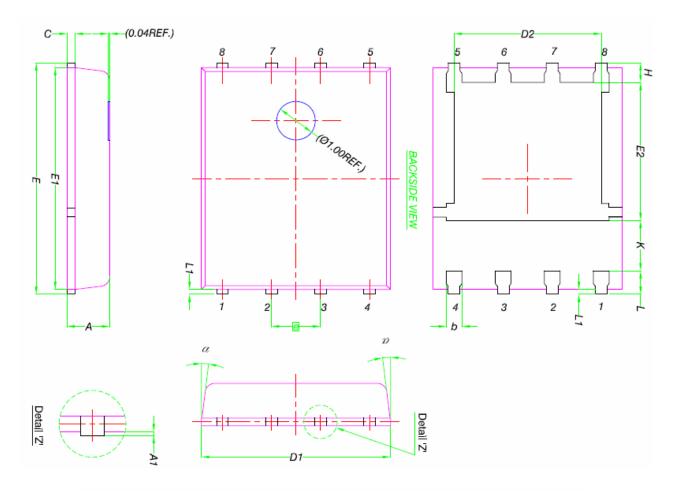


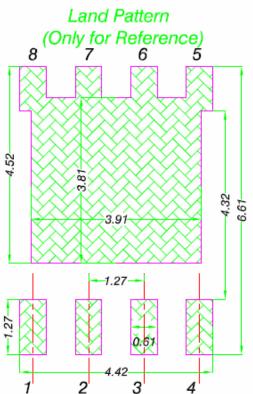
Figure 11 Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package Information



| | MILLIMETERS | | | | |
|------|-------------|---|------|--|--|
| DIM. | MIN. | NOM. 1.00 - 0.41 0.25 4.90 3.81 6.00 5.75 3.58 | MAX. | | |
| Α | 0.90 | 1.00 | 1.10 | | |
| A1 | 0 | - | 0.05 | | |
| b | 0.33 | 0.41 | 0.51 | | |
| С | 0.20 | 0.25 | 0.30 | | |
| D1 | 4.80 | 4.90 | 5.00 | | |
| D2 | 3.61 | 3.81 | 3.96 | | |
| E | 5.90 | 6.00 | 6.10 | | |
| E1 | 5.70 | 5.75 | 5.80 | | |
| E2 | 3.38 | 3.58 | 3.78 | | |
| е | 1.27 BSC | | | | |
| Н | 0.41 | 0.51 | 0.61 | | |
| к | 1.10 | - | - | | |
| L | 0.51 | 0.61 | 0.71 | | |
| L1 | 0.06 | 0.13 | 0.20 | | |
| α | 0° | - | 12° | | |





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